## NSN 5961-01-089-9897

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View Online at https://aerobasegroup.com/nsn/5961-01-089-9897 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.761 inches **Overall Height:** 0.300 inches **Overall Width:** 0.980 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage/static/emitter open and 33.0 collector to emitter voltage/static/base open and 65.0 collector to emitter reverse voltage, with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 140.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Contains beryllium oxide; junction pattern arrangement: npn **Test Data Document:** 13499-352-1090 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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No